## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE.

Application No. 10/595 660 Confirmation No. 4264

May 3, 2005

Yuichiro Shindo Applicant

Art Unit

371(c) Date Examiner

Customer No. 00270

Title HIGH PURITY HAFNIUM, TARGET AND THIN FILM

COMPRISING SAID HIGH PURITY HAFNIUM. AND METHOD FOR PRODUCING HIGH PURITY HAFNIUM

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## INFORMATION DISCLOSURE STATEMENT

Dear Sir

In compliance with their duty to disclose under 37 CFR \$1.56(a). Applicants and their attorneys enclose a form PTO-1449 and copies of the foreign and other documents listed therein.

The listed references were cited in the International Search Report for International Application No. PCT/JP04/15777, or are discussed on page 2 of the present application, or are related U.S. or European patent documents. Co-pending U.S. Patent Application No. 10/565,767 filed on January 24, 2006 is cited with respect to double patenting issues only.

The Examiner is respectfully requested to consider the cited documents and to make the same of record in the file of the present application.

In the event that a fee for the Information Disclosure Statement is required, please charge the fee to our Deposit Account No. 08-3040.

Respectfully submitted, HOWSON AND HOWSON Attorneys for Applicant

By /William Bak/

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Form	PTO-1449
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INFO	DRMATION DISCLOSURE
STA	TEMENT

## Atty. Docket No. OGOSH53USA

Serial No. 10/595,660

Applicant: Yuichiro Shindo 371 (c) Date: May 3, 2006

Group Art Unit:

	U.S. PA	TENT DOC	UMENIS		
Examiner Initial	Document No.	Date	Name	Class	Subclass
	6,861,030 B2	3/2005	Shindo	420	422
	6,737,030 B2	5/2004	Sommers et al.	423	70
	4,897,116	1/1990	Scheel	75	84.5
	4,668,287	5/1987	Kwon	75	84.5
	4,637,831	1/1987	Stoltz et al.	75	84.5

## FOREIGN PATENT DOCUMENTS

Examiner Initial	Document No.	Date	Country	Translation Yes No	
	JP 04-358030	12/1992	Japan	Abstract only	Х
	JP 07-316681	12/1995	Japan	Abstract only	X
	JP 2003-193150	7/2003	Japan	Abstract only	X
	JP 04-099829	3/1992	Japan	Abstract only	X
	JP 2000-345252	6/1999	Japan	Abstract only	Х
	EP 0154448 A2	9/1985	European		
	EP 0134643 A2	3/1985	European		

Other Documents (including Author, Title, Date, Pertinent Pages, Etc.)

	Esp@cenet, One Page English Abstract of JP 10-204554, August 1998
	Esp@cenet, One Page English Abstract of JP 61-242993, October 1986
	Co-pending U.S. Patent Application No. 10/565,767 filed January 24, 2006

Date Considered

\*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609: Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.